

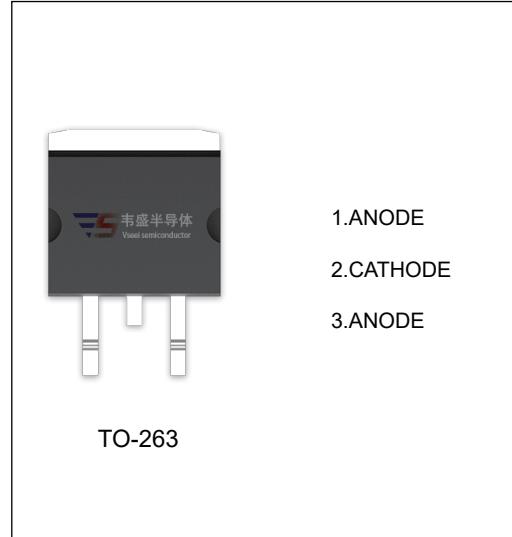
SBDB20150CT SCHOTTKY BARRIER RECTIFIER

MAIN CHARACTERISTICS

I_O	20 (2×10) A
V_{RRM}	150 V
T_j	150 °C
V_{F(typ)}	0.71V (@Tj=125°C)

FEATURES

- Low Power Loss, High Efficiency
- Guard Ring Die Construction for Transient Protection
- High Current Capability and Low Forward Voltage Drop



MAXIMUM RATINGS (T_a=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{RRM}	Peak repetitive reverse voltage	150	V
V_{RWM}	Working peak reverse voltage		
V_R	DC blocking voltage		
V_{R(RMS)}	RMS reverse voltage	105	V
I_O	Average rectified output current	20	A
I_{FSM}	Non-Repetitive peak forward surge current (8.3ms half sine wave)	150	A
R_{θJC}	Thermal resistance from junction to case , T _c =25°C	2.0	°C/W
R_{θJA}	Thermal resistance from junction to ambient	62.5	°C/W
T_j	Junction temperature	150	°C
T_{stg}	Storage temperature	-55~+150	°C

ELECTRICAL CHARACTERISTICS (T_a=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse voltage	V_(BR)	I_R=0.1mA	150			V
Reverse current	I_R	V_R=150V	T_j =25°C	2.0	100	uA
			T_j =125°C	2.0		mA
Forward voltage	V_F	I_F=5A	T_j =25°C	0.76		V
			T_j =125°C	0.64		V
		I_F=10A	T_j =25°C	0.83	0.90	V
			T_j =125°C	0.71		V

*Pulse test: pulse width ≤300μs, duty cycle≤ 2.0%.

FIG.1: FORWARD CURRENT DERATING CURVE

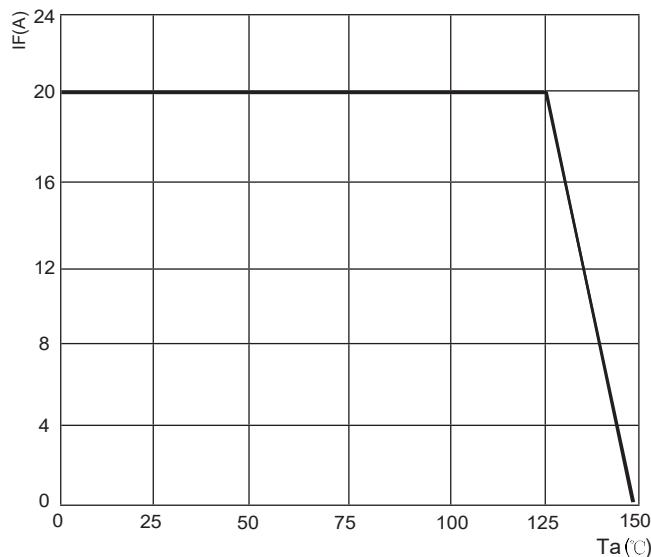


FIG.2: TYPICAL FORWARD CHARACTERISTICS

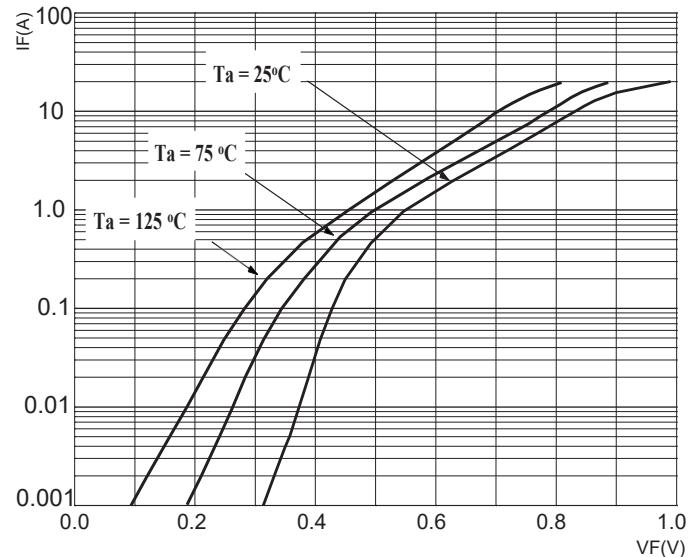


FIG.3: TOTAL CAPACITANCE DERATING CURVE

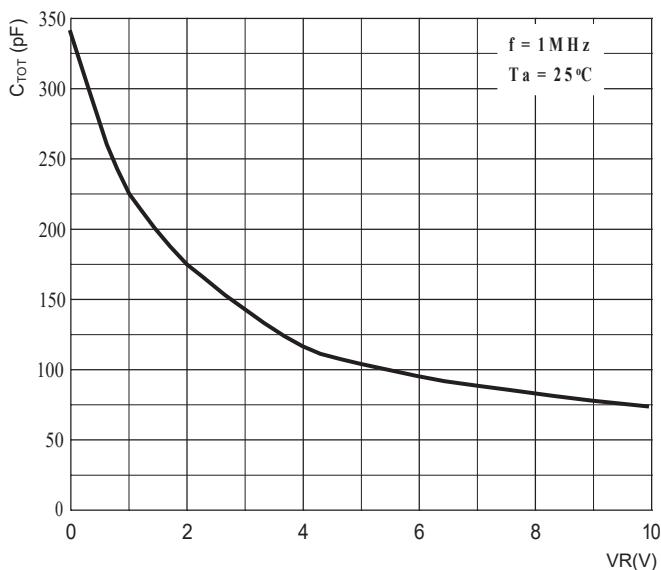


FIG.4: TYPICAL REVERSE CHARACTERISTICS

